



PRODUCT SPECIFICATION

Model No : CSM-57071E/CSM-57081E

Descriptions:
<ul style="list-style-type: none"> • 0.7Inch Dot-Matrix Display • 5*7 Array with X-Y Select. • CSM-57071: Column Anode, Row Cathode • CSM-57081: Column Cathode, Row Anode • Emitting Color: Orange



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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Model No : CSM-57071E/CSM-57081E

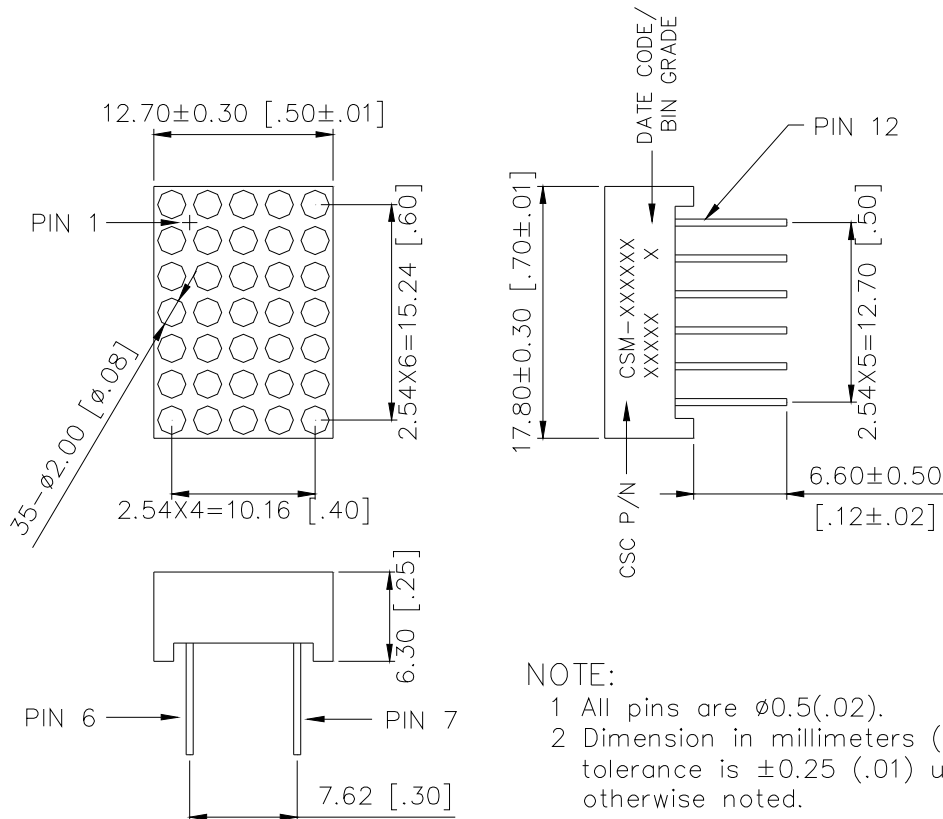
Features -

1. 0.7 inch (17.2mm) Matrix height.
2. Case mold type.
3. RoHs compliant.
4. Low power consumption.
5. Easy mounting on P.C. board or socket.

Device Selection Guide -

Part No.	Chip		Description	
	Material	Emitted Color	Column	Row
CSM-57071E	GaAsP	Orange	Anode	Cathode
CSM-57081E			Cathode	Anode

Package Dimensions -



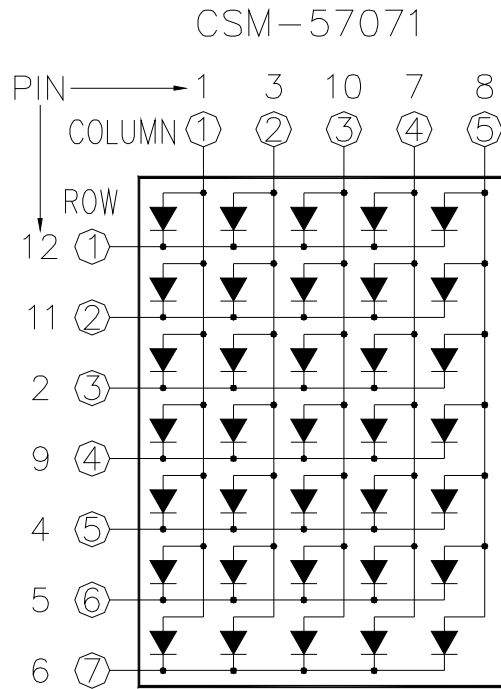
NOTE:

- 1 All pins are $\phi 0.5$ (.02).
- 2 Dimension in millimeters (inch), tolerance is ± 0.25 (.01) unless otherwise noted.



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Internal Circuit Diagrams -



CSM-57071				CSM-57081			
PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION
1	Anode Column 1	7	Anode Column 4	1	Cathode Column 1	7	Cathode Column 4
2	Cathode Row 3	8	Anode Column 5	2	Anode Row 3	8	Cathode Column 5
3	Anode Column 2	9	Cahtode Row 4	3	Cathode Column 2	9	Anode Row 4
4	Cathode Row 5	10	Anode Column 3	4	Anode Row 5	10	Cathode Column 3
5	Cathode Row 6	11	Cathode Row 2	5	Anode Row 6	11	Anode Row 2
6	Cathode Row 7	12	Cathode Row 1	6	Anode Row 7	12	Anode Row 1



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■ Absolute Maximum Rating -

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	PAD	70	mW
Continuous Forward Current Per Dice	IAF	25	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	IPF	90	mA
Derating Linear From 25°C Per Dice	-	0.33	mA/°C
Reverse Voltage Per Dice	VR	5	V
Operating Temp.	Topr	-35 ~ +85	°C
Storage Temp.	Tstg	-35 ~ +85	°C
Solder temperature 1/16 inch below seating plane for 3 seconds at 260°C			

■ Electro-optical Characteristics -

(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	VF	-	2.1	2.8	V	IF=20mA
Luminous Intensity Per Segment	Iv	-	3800	-	ucd	IF=10mA
Peak Emission Wavelength	λ_p	-	632	-	nm	IF=20mA
Dominant Wavelength	λ_d	-	624	-	nm	IF=20mA
Spectrum Radiation Bandwidth	$\Delta \lambda$	-	35	-	nm	IF=20mA
Reverse Current	IR	-	-	100	μA	VR=5V
Luminous Intensity Matching Ratio	IV-m	-	-	2:1		Ip=80mA 1/16Duty



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Typical Electrical / Optical Characteristics Curves -

($T_a = 25^\circ\text{C}$ Unless Otherwise Noted)

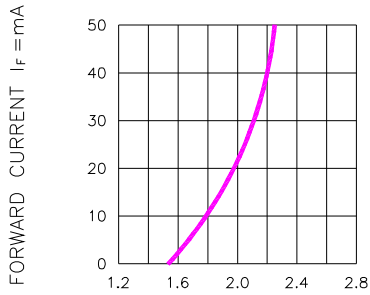


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

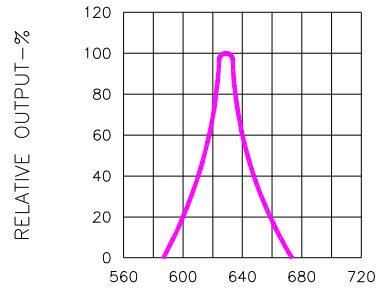


Fig.2 SPECTRAL RESPONSE

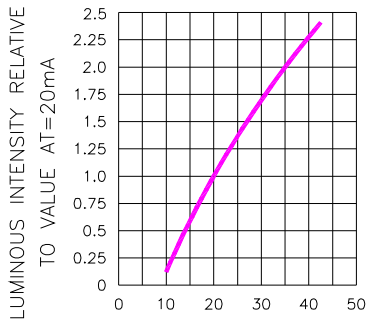


Fig.3 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

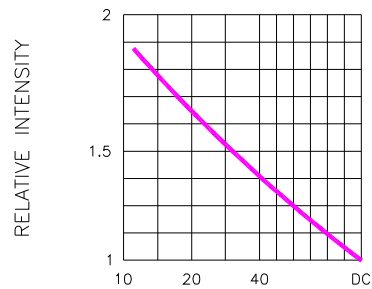


Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

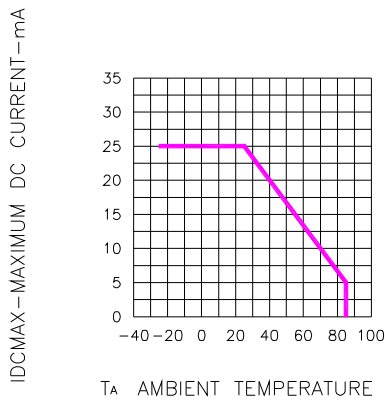


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE

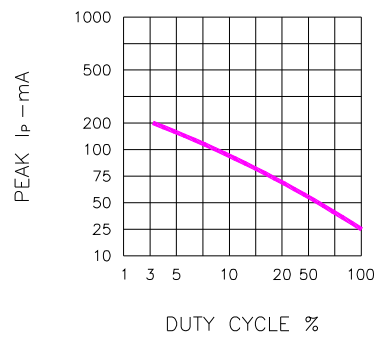


Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE $f=1\text{ KHz}$)

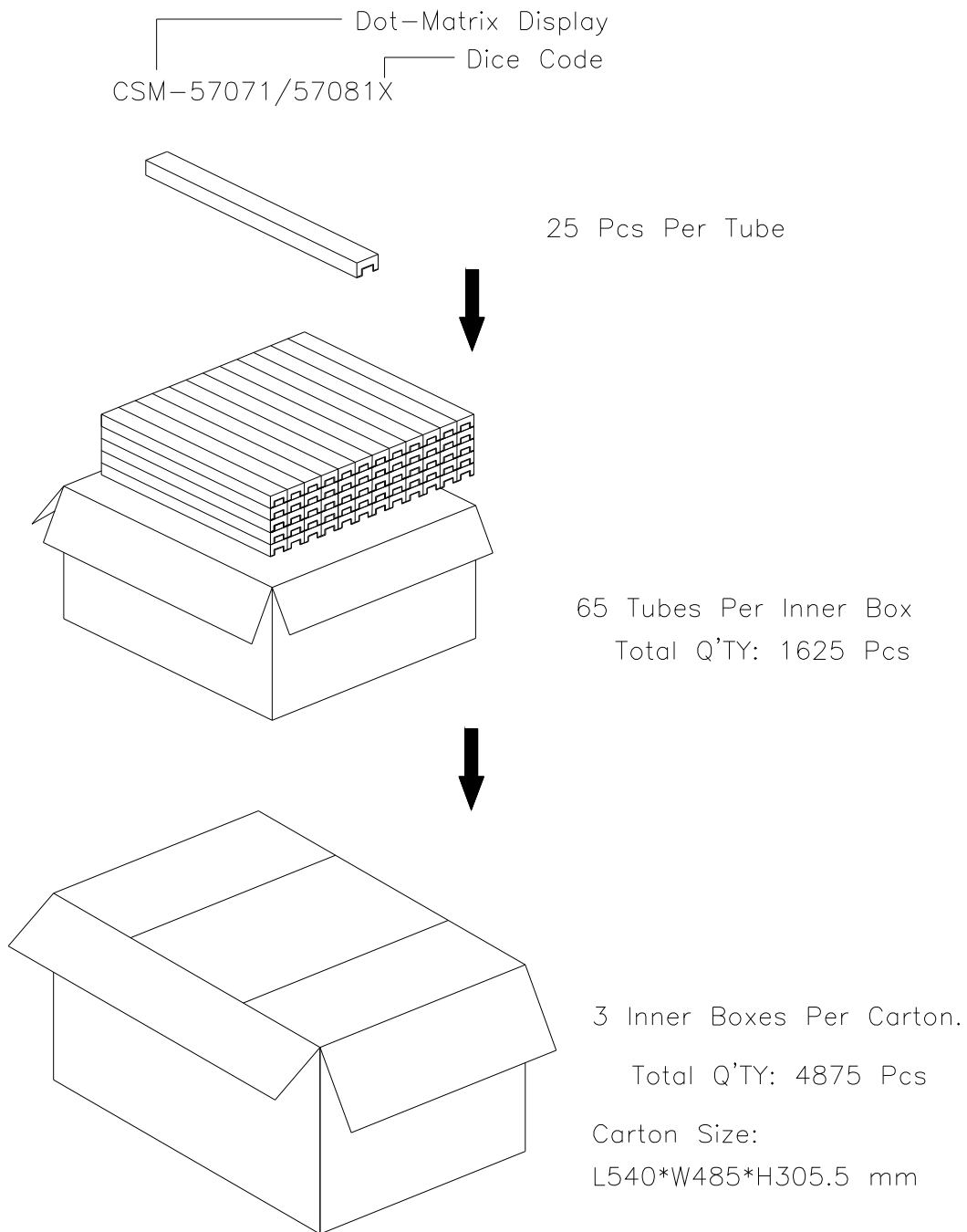


**CHINA
SEMICONDUCTOR
CORPORATION**

Spec. No.	PS-ND-0710
Rev.	A

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■ Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.